



DESIGNER'S KIT K3-ERASM+

Wideband Amplifiers

50Ω DC to 4 GHz

Mini-Circuits



FEATURES

- Wideband, 50 Ω
- Up to +18.4 dBm typ. output power
- Low thermal resistance
- Miniature microwave amplifier
- Plastic micro-x surface mount package

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SPEED UP
THE SOLUTION



Evaluation boards available.
See individual model data sheets.



K3-ERASM+ ELECTRICAL SPECIFICATIONS

(kit includes 3 models, 10 of each, 30 total)

Model	Freq. ¹ (GHz)	Gain (dB) Typical						Maximum Power (dBm) @ 1 GHz			Dynamic Range @ 1 GHz		VSWR (:1) Typ.				Absolute Max. Rating ²		DC ³ Operating Power @ pin 3			Therm. Resist.	Evaluation Board	
		Over frequency, GHz						Output (1dB Compr.)		NF (dB) Typ.	IP3 (dBm) Typ.	In DC-3 GHz	In 3-f _u GHz	Out DC-3 GHz	Out 3-f _u GHz	I (mA)	P (mW)	Cur- rent (mA)	Device Volt.			θ _{jc} Typ. °C/W		
		0.1	1	2	3	4	Min @ 2 GHz	Typ.	Min										Typ.	Typ.	Min.			Max
ERA-4SM+	DC-4	14.3	14.0	13.4	12.7	11.8	11	17.3	15.0	20.0	4.2	34.0	1.2	1.2	1.3	1.8	120	650	65	4.5	4.2	5.5	196	TB-408-4+
ERA-5SM+	DC-4	20.2	19.5	17.6	15.6	14.0	16	18.4	16.5	13.0	4.3	32.5	1.3	1.3	1.2	1.3	120	650	65	4.9	4.2	5.5	133	TB-408-5+
ERA-6SM+	DC-4	12.6	12.5	12.2	11.7	11.3	10.5	17.9	16.0	20.0	4.5	36.0	1.3	1.2	1.6	1.8	120	650	70	5.0	4.6	5.6	143	TB-408-6+

1. Low frequency cutoff determined by external coupling capacitors. f_u is the upper frequency limit for each model.

2. Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

3. Supply voltage must be connected to pin 3 through a bias resistor in order to prevent damage. See "Biasing MMIC Amplifiers" at minicircuits.com/applications.shtml.

Reliability predictions are applicable at specified current and normal operating conditions.

